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Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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SILICON POWER MOS FET NE552R479A

3.0 V OPERATION SILICON RF POWER LDMOS FET FOR 2.45 GHz 0.4 W TRANSMISSION AMPLIFIERS

DESCRIPTION

The NE552R479A is an N-channel silicon power laterally diffused MOS FET specially designed as the transmission power amplifier for 3.0 V WLL products. Dies are manufactured using our NEWMOS2 technology (our WSi gate laterally diffused MOS FET) and housed in a surface mount package. This device can deliver 26.0 dBm output power with 45% power added efficiency at 2.45 GHz under the 3.0 V supply voltage.

FEATURES

: Pout = 26.0 dBm TYP. (VDS = 3.0 V, IDset = 200 mA, f = 2.45 GHz, Pin = 19 dBm) · High output power High power added efficiency: η_{add} = 45% TYP. (V_{DS} = 3.0 V, l_{Dset} = 200 mA, f = 2.45 GHz, P_{in} = 19 dBm) High linear gain : GL = 11 dB TYP. (VDS = 3.0 V, IDset = 200 mA, f = 2.45 GHz, Pin = 10 dBm)

 Surface mount package $: 5.7 \times 5.7 \times 1.1 \text{ mm MAX}.$

· Single supply : $V_{DS} = 2.8 \text{ to } 6.0 \text{ V}$

APPLICATIONS

 Digital cellular phones : 3.0 V GSM1900 Pre Driver Analog cellular phones : 2.8 V AMPS Handsets Bluetooth[™] applications : 3.0 V Class 1 Devices Others : 3.0 V Two-Way Pagers

ORDERING INFORMATION

Part Number	Package	Marking	Supplying Form
NE552R479A-T1	79A	AW	12 mm wide embossed tapingGate pin face the perforation side of the tapeQty 1 kpcs/reel
NE552R479A-T1A		12 mm wide embossed taping Gate pin face the perforation side of the tape Qty 5 kpcs/reel	

Remark To order evaluation samples, contact your nearby sales office.

Part number for sample order: NE552R479A

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

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Document No. PU10124EJ03V0DS (3rd edition) Date Published July 2003 CP(K)

ABSOLUTE MAXIMUM RATINGS (TA = +25°C)

Parameter	Symbol	Ratings	Unit
Drain to Source Voltage	Vos	15.0	V
Gate to Source Voltage	Vgs	5.0	V
Drain Current	lσ	300	mA
Drain Current (Pulse Test)	I _D Note	600	mA
Total Power Dissipation	Ptot	10	W
Channel Temperature	Tch	125	°C
Storage Temperature	T _{stg}	-55 to +125	°C

Note Duty Cycle 50%, $T_{on} \le 1 \text{ s}$

RECOMMENDED OPERATING CONDITIONS

Parameter Symbol **Test Conditions** MIN. TYP. MAX. Unit Drain to Source Voltage V_{DS} 2.8 3.0 V 6.0 Gate to Source Voltage Vgs 0 2.0 3.0 ٧ **Drain Current** Duty Cycle 50%, Ton ≤ 1 s 200 500 mΑ ΙD Input Power $f = 2.45 \text{ GHz}, V_{DS} = 3.0 \text{ V}$ 18 19 dBm

ELECTRICAL CHARACTERISTICS

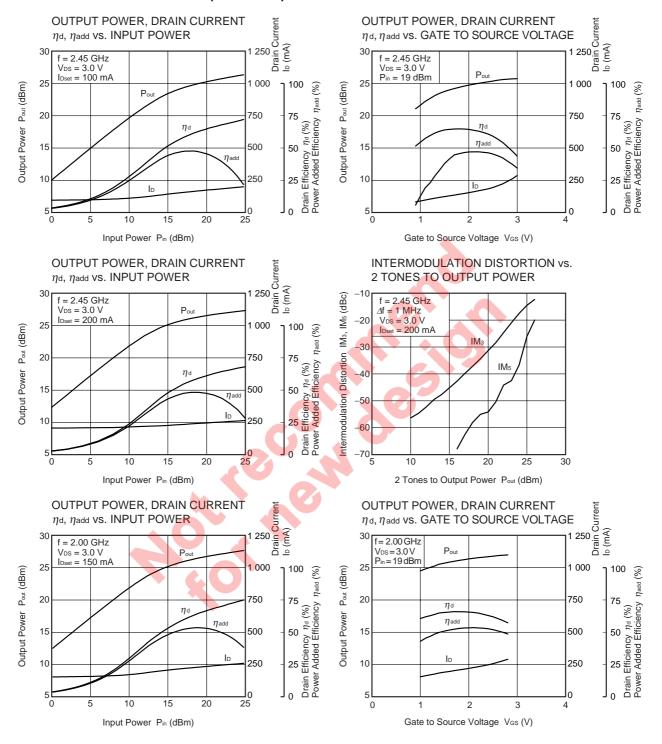
(TA = +25°C, unless otherwise specified, using NEC standard test fixture)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Gate to Source Leak Current	Igss	Vgs = 5.0 V	-	_	100	nA
Drain to Source Leakage Current (Zero Gate Voltage Drain Current)	IDSS	V _{DS} = 6.0 V	ı	ı	100	nA
Gate Threshold Voltage	V_{th}	V _{DS} = 3.5 V, I _D = 1 mA	1.0	1.4	1.9	V
Thermal Resistance	Rth	Channel to Case	-	-	10	°C/W
Transconductance	Gm	V _{DS} = 3.5 V, I _D = 100 mA	-	0.4	-	S
Drain to Source Breakdown Voltage	BV _{DSS}	$I_{DSS} = 10 \ \mu A$	15	18	-	V
Output Power	Pout	f = 2.45 GHz, V _{DS} = 3.0 V,	24.0	26.0	-	dBm
Drain Current	lσ	P _{in} = 19 dBm,	-	230	-	mA
Power Added Efficiency	η add	I _{Dset} = 200 mA (RF OFF), Note1	35	45	_	%
Linear Gain Note2	G∟		1	11	-	dB

Notes 1. DC performance is 100% testing. RF performance is testing several samples per wafer. Wafer rejection criteria for standard devices is 1 reject for several samples.

2. $P_{in} = 10 \text{ dBm}$

TYPICAL CHARACTERISTICS (TA = +25°C)



Remark The graphs indicate nominal characteristics.

S-PARAMETERS

S-parameters/Noise parameters are provided on the NEC Compound Semiconductor Devices Web site in a form (S2P) that enables direct import to a microwave circuit simulator without keyboard input.

Click here to download S-parameters.

[RF and Microwave] → [Device Parameters]

URL http://www.csd-nec.com/

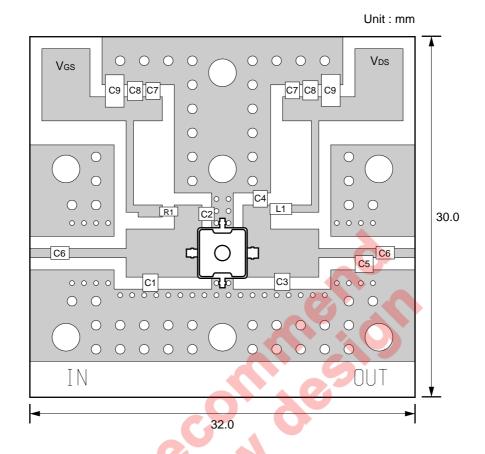
LARGE SIGNAL IMPEDANCE (VDS = 3.0 V, ID = 200 mA, f = 2.45 GHz, Pout = 400 mW)

f (GHz)	$Z_{in}\left(\Omega \right)$	$ZoL\left(\Omega ight)^{Note}$		
2.45	2.96 -j7.78	3.36 -j8.42		

Note ZoL is the conjugate of optimum load impedance at given voltage, idling current, input power and frequency.



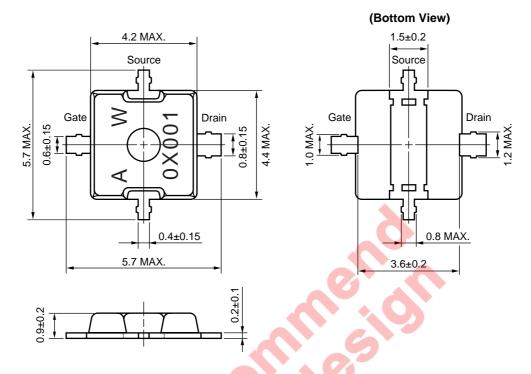
★ EVALUATION BOARD FOR 2.45 GHz



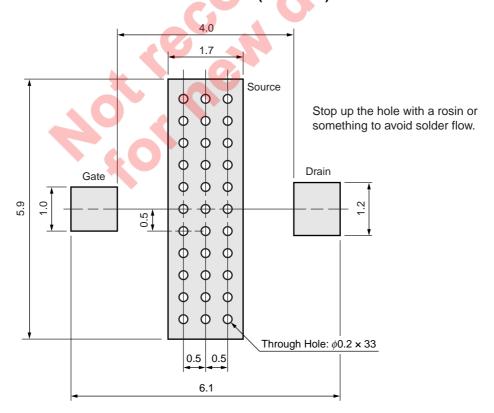
Symbol	Value	Comment
C1	2.0 pF	
C2	1.4 pF	
C3	2.2 pF	
C4	0.8 pF	
C5	0.5 pF	
C6	10 pF	
C7	1 000 pF	
C8	0.22 μF	
C9	3.3 μF - 16V	
R1	1 000 Ω	
L1	22 nH	
Circuit Board	$t = 0.4$ mm, ε $r = 4.5$	R4775

▶ PACKAGE DIMENSIONS

79A (UNIT: mm)



79A PACKAGE RECOMMENDED P.C.B. LAYOUT (UNIT: mm)





RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions		Condition Symbol
Infrared Reflow	Peak temperature (package surface temperature) Time at peak temperature Time at temperature of 220°C or higher Preheating time at 120 to 180°C Maximum number of reflow processes Maximum chlorine content of rosin flux (% mass)	: 260°C or below : 10 seconds or less : 60 seconds or less : 120±30 seconds : 3 times : 0.2%(Wt.) or below	IR260
VPS	Peak temperature (package surface temperature) Time at temperature of 200°C or higher Preheating time at 120 to 150°C Maximum number of reflow processes Maximum chlorine content of rosin flux (% mass)	: 215°C or below : 25 to 40 seconds : 30 to 60 seconds : 3 times : 0.2%(Wt.) or below	VP215
Wave Soldering	Peak temperature (molten solder temperature) Time at peak temperature Preheating temperature (package surface temperature) Maximum number of flow processes Maximum chlorine content of rosin flux (% mass)	: 260°C or below : 10 seconds or less : 120°C or below : 1 time : 0.2%(Wt.) or below	WS260
Partial Heating	Peak temperature (pin temperature) Soldering time (per pin of device) Maximum chlorine content of rosin flux (% mass)	: 350°C or below : 3 seconds or less : 0.2%(Wt.) or below	HS350-P3

Caution Do not use different soldering methods together (except for partial heating).

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M8E 00.4-0110



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